<u>Voltage Regulator</u> - Low Dropout

300 mA

The MC33275 series are micropower low dropout voltage regulators available in a wide variety of output voltages as well as packages, SOT-223, SOP-8, DPAK, and DFN 4x4 surface mount packages. These devices feature a very low quiescent current and are capable of supplying output currents up to 300 mA. Internal current and thermal limiting protection are provided by the presence of a short circuit at the output and an internal thermal shutdown circuit.

Due to the low input-to-output voltage differential and bias current specifications, these devices are ideally suited for battery powered computer, consumer, and industrial equipment where an extension of useful battery life is desirable.

Features

- Low Input–to–Output Voltage Differential of 25 mV at I_O = 10 mA, and 260 mV at I_O = 300 mA
- Extremely Tight Line and Load Regulation
- $\bullet\,$ Stable with Output Capacitance of only 0.33 μF for 2.5 V Output Voltage
- Internal Current and Thermal Limiting
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free Devices

Applications

- Battery Powered Consumer Products
- Hand-Held Instruments
- Camcorders and Cameras

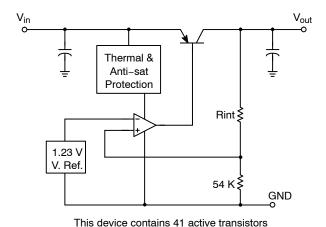


Figure 1. Simplified Block Diagram

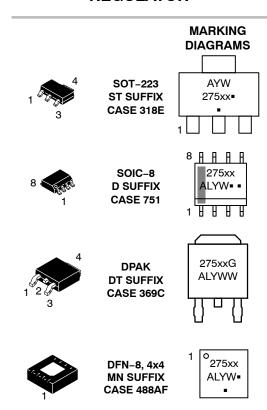
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LOW DROPOUT MICROPOWER VOLTAGE REGULATOR



ORDERING INFORMATION

= Voltage Version

= Wafer Lot

■ or G = Pb-Free Device

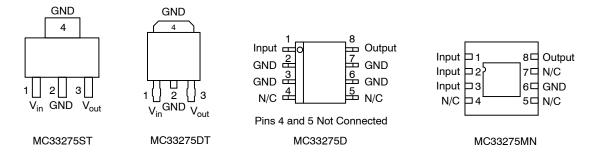
Y = Year W, WW = Work Week

= Assembly Location

(Note: Microdot may be in either location)

See detailed ordering and shipping information on page 10 of this data sheet.

PIN CONNECTIONS



MAXIMUM RATINGS

Vdc W °C/W °C/W °C/W
°C/W °C/W
°C/W °C/W
°C/W °C/W
°C/W
°C/W
°C/M
$^{\circ}C.\Lambda M$
°C/W
°C/W
°C/W
0000
°C/W
°C/W
°C/W
mA
°C
°C
°C
V
٧

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

^{*&}quot;C" ("case") is defined as the solder–attach interface between the center of the exposed pad on the bottom of the package, and the board to which it is attached.

$\textbf{ELECTRICAL CHARACTERISTICS} \ (C_L = 1.0 \mu F, \ T_A = 25 ^{\circ}C, \ for \ min/max \ values \ T_J = -40 ^{\circ}C \ to \ +125 ^{\circ}C, \ Note \ 1)$

	Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage 2.5 V Suffix 3.0 V Suffix 3.3 V Suffix 5.0 V Suffix	$I_O = 0$ mA to 250 mA $T_A = 25^{\circ}C$, $V_{in} = [V_O + 1] V$	Vo	2.475 2.970 3.267 4.950	2.50 3.00 3.30 5.00	2.525 3.030 3.333 5.05	Vdc
2.5 V Suffix 3.0 V Suffix 3.3 V Suffix 5.0 V Suffix	$V_{in} = [V_O + 1] V$, $0 < I_O < 100 \text{ mA}$ 2% Tolerance from $T_J = -40 \text{ to } +125^{\circ}\text{C}$		2.450 2.940 3.234 4.900	- - - -	2.550 3.060 3.366 5.100	
Line Regulation	V_{in} = [V _O + 1] V to 12 V, I _O = 250 mA, All Suffixes T _A = 25°C	Reg _{line}	-	2.0	10	mV
Load Regulation	V_{in} = [V _O + 1] V, I _O = 0 mA to 250 mA, All Suffixes T _A = 25°C	Reg _{load}	-	5.0	25	mV
Dropout Voltage $I_O = 10 \text{ mA}$ $I_O = 100 \text{ mA}$ $I_O = 250 \text{ mA}$ $I_O = 300 \text{ mA}$	$T_{J} = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	V _{in} – V _O	- - - -	25 115 220 260	100 200 400 500	mV
Ripple Rejection	(120 Hz) $V_{in(peak-peak)} = [V_O + 1.5] V \text{ to } [V_O + 5.5] V$	-	65	75	-	dB
Output Noise Volt $C_L = 1.0 \ \mu F$ $C_L = 200 \ \mu F$	age I _O = 50 mA (10 Hz to 100 kHz)	V _n	- -	160 46	- -	μVrms
CURRENT PARAI	METERS					
Quiescent Curren	t ON Mode $V_{in} = [V_O + 1] V, I_O = 0 mA$	I _{QOn}	-	125	200	μΑ

Quiescent Current ON Mode	$V_{in} = [V_O + 1] V, I_O = 0 mA$	I _{QOn}	-	125	200	μΑ
Quiescent Current ON Mode SAT 3.0 V Suffix 3.3 V Suffix 5.0 V Suffix	$V_{in} = [V_O - 0.5] V, I_O = 0 \text{ mA (Notes 2, 3)}$	I _{QSAT}	- - -	1500 1500 1500	2000 2000 2000	μΑ
Current Limit	V _{in} = [V _O + 1] V, V _O Shorted	I _{LIMIT}	_	450	_	mA

THERMAL SHLITDOWN

THERMAL SHOTDOWN						
Thermal Shutdown	-	-	150	-	°C	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- Low duty pulse techniques are used during test to maintain junction temperature as close to ambient as possible.
 Quiescent Current is measured where the PNP pass transistor is in saturation. V_{in} = [V_O 0.5] V guarantees this condition.
- 3. For 2.5 V version, $I_{\mbox{QSAT}}$ is constrained by the minimum input voltage of 2.5 V.

DEFINITIONS

Load Regulation – The change in output voltage for a change in load current at constant chip temperature.

Dropout Voltage – The input/output differential at which the regulator output no longer maintains regulation against further reductions in input voltage. Measured when the output drops 100 mV below its nominal value (which is measured at 1.0 V differential), dropout voltage is affected by junction temperature, load current and minimum input supply requirements.

Output Noise Voltage – The RMS AC voltage at the output with a constant load and no input ripple, measured over a specified frequency range.

Maximum Power Dissipation – The maximum total dissipation for which the regulator will operate within specifications.

Quiescent Current – Current which is used to operate the regulator chip and is not delivered to the load.

Line Regulation – The change in output voltage for a change in the input voltage. The measurement is made under conditions of low dissipation or by using pulse techniques such that the average chip temperature is not significantly affected.

Maximum Package Power Dissipation – The maximum package power dissipation is the power dissipation level at which the junction temperature reaches its maximum value i.e. 150° C. The junction temperature is rising while the difference between the input power ($V_{CC} \times I_{CC}$) and the output power ($V_{out} \times I_{out}$) is increasing.

Depending on ambient temperature, it is possible to calculate the maximum power dissipation and so the maximum current as following:

$$Pd = \frac{T_J - T_A}{R_{\theta,JA}}$$

The maximum operating junction temperature T_J is specified at 150°C, if $T_A = 25$ °C, then P_D can be found. By neglecting the quiescent current, the maximum power dissipation can be expressed as:

$$I_{out} = \frac{P_D}{V_{CC} - V_{out}}$$

The thermal resistance of the whole circuit can be evaluated by deliberately activating the thermal shutdown of the circuit (by increasing the output current or raising the input voltage for example).

Then you can calculate the power dissipation by subtracting the output power from the input power. All variables are then well known: power dissipation, thermal shutdown temperature and ambient temperature.

$$R_{\theta JA} = \frac{T_J - T_A}{P_D}$$

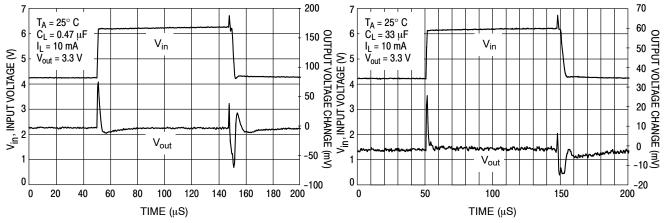


Figure 2. Line Transient Response

Figure 3. Line Transient Response

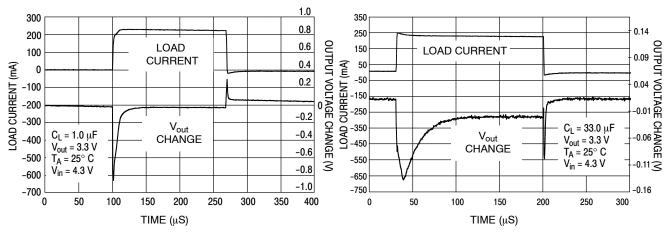


Figure 4. Load Transient Response

Figure 5. Load Transient Response

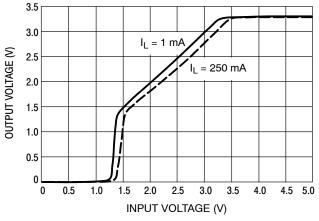


Figure 6. Output Voltage versus Input Voltage

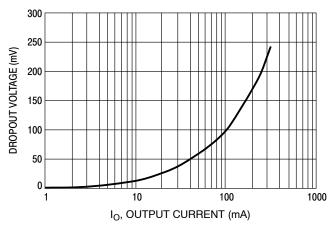


Figure 7. Dropout Voltage versus Output Current

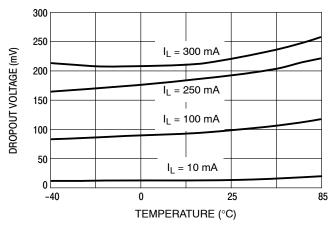


Figure 8. Dropout Voltage versus Temperature

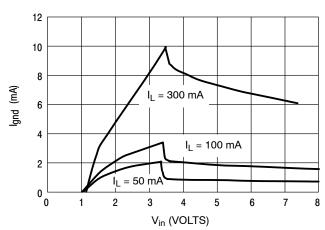


Figure 9. Ground Pin Current versus Input Voltage

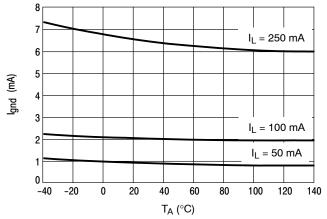


Figure 10. Ground Pin Current versus Ambient Temperature

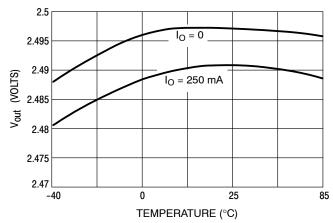


Figure 11. Output Voltage versus Ambient Temperature ($V_{in} = V_{out} + 1V$)

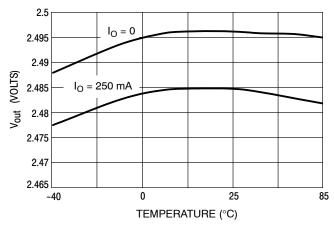


Figure 12. Output Voltage versus Ambient Temperature (V_{in} = 12 V)

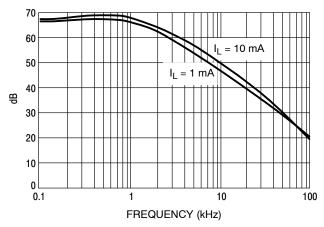


Figure 13. Ripple Rejection

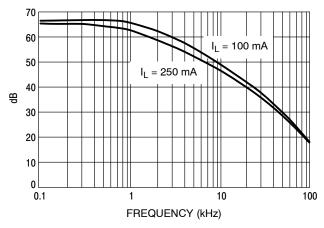


Figure 14. Ripple Rejection

APPLICATIONS INFORMATION

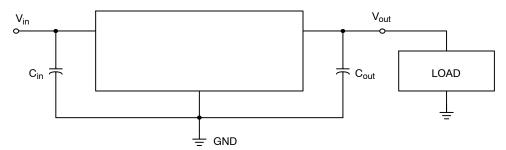


Figure 15. Typical Application Circuit

The MC33275 regulators are designed with internal current limiting and thermal shutdown making them user–friendly. Figure 15 is a typical application circuit. The output capability of the regulator is in excess of 300 mA, with a typical dropout voltage of less than 260 mV. Internal protective features include current and thermal limiting.

EXTERNAL CAPACITORS

These regulators require only a 0.33 µF (or greater) capacitance between the output and ground for stability for 1.8 V, 2.5 V, 3.0 V, and 3.3 V output voltage options. Output voltage options of 5.0 V require only 0.22 µF for stability. The output capacitor must be mounted as close as possible to the MC33275. If the output capacitor must be mounted further than two centimeters away, then a larger value of output capacitor may be required for stability. A value of 0.68 µF or larger is recommended. Most type of aluminum, tantalum, or multilayer ceramic will perform adequately. Solid tantalums or appropriate multilayer ceramic capacitors are recommended for operation below 25°C. An input bypass capacitor is recommended to improve transient response or if the regulator is connected to the supply input filter with long wire lengths, more than 4 inches. This will reduce the circuit's sensitivity to the input line impedance at high frequencies. A 0.33 µF or larger tantalum, mylar, ceramic, or other capacitor having low internal impedance at high frequencies should be chosen. The bypass capacitor should be mounted with shortest possible lead or track length directly across the regulator's input terminals. Figure 16 shows the ESR that allows the LDO to remain stable for various load currents.

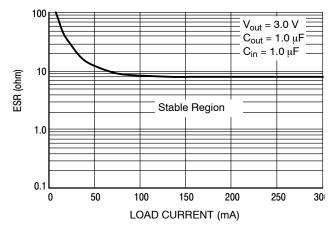


Figure 16. ESR for V_{out} = 3.0V

Applications should be tested over all operating conditions to insure stability.

THERMAL PROTECTION

Internal thermal limiting circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When activated, typically at 150°C, the output is disabled. There is no hysteresis built into the thermal protection. As a result the output will appear to be oscillating during thermal limit. The output will turn off until the temperature drops below the 150°C then the output turns on again. The process will repeat if the junction increases above the threshold. This will continue until the existing conditions allow the junction to operate below the temperature threshold.

Thermal limit is not a substitute for proper heatsinking.

The internal current limit will typically limit current to 450 mA. If during current limit the junction exceeds 150°C, the thermal protection will protect the device also. **Current limit is not a substitute for proper heatsinking.**

OUTPUT NOISE

In many applications it is desirable to reduce the noise present at the output. Reducing the regulator bandwidth by increasing the size of the output capacitor will reduce the noise.

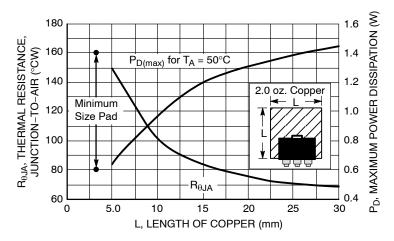


Figure 17. SOT-223 Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

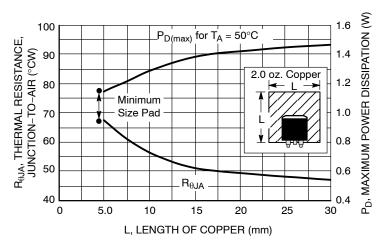


Figure 18. DPAK Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

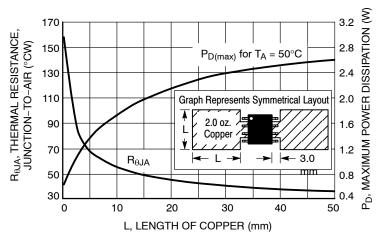


Figure 19. SOP-8 Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

ORDERING INFORMATION

Device	V _O Typ (V)	Operating Temperature Range, Tolerance	Case	Package	Marking	Shipping [†]
MC33275D-2.5G			751	SOIC-8 (Pb-Free)	27525	98 Units/Rail
MC33275D-2.5R2G	1		751	SOIC-8 (Pb-Free)	27525	2500/Tape & Reel
MC33275DT-2.5G	2.5 V		369A	DPAK (Pb-Free)	27525G	75 Units/Rail
MC33275DT-2.5RKG	(Fixed Voltage)		369A	DPAK (Pb-Free)	27525G	2500/Tape & Reel
MC33275MN-2.5R2G	-	1% Tolerance at T _A = 25°C	488AF	DFN8 (Pb-Free)	27525	3000/Tape & Reel
MC33275ST-2.5T3G			318E	SOT-223 (Pb-Free)	27525	4000/Tape & Reel
MC33275D-3.0G			751	SOIC-8 (Pb-Free)	27530	98 Units/Rail
MC33275D-3.0R2G	-	2% Tolerance at T ₁ from -40°C to +125°C	751	SOIC-8 (Pb-Free)	27530	2500/Tape & Reel
MC33275DT-3.0G	3.0 V	15 15 15 15 15 15 15 15 15 15 15 15 15 1	369A	DPAK (Pb-Free)	27530G	75 Units/Rail
MC33275DT-3.0RKG	(Fixed Voltage)		369A	DPAK (Pb-Free)	27530G	2500/Tape & Reel
MC33275MN-3.0R2G	-		488AF	DFN8 (Pb-Free)	27530	3000/Tape & Reel
MC33275ST-3.0T3G	-		318E	SOT-223 (Pb-Free)	27530	4000/Tape & Reel
MC33275D-3.3G			751	SOIC-8 (Pb-Free)	27533	98 Units/Rail
MC33275D-3.3R2G		1% Tolerance at T _A = 25°C	751	SOIC-8 (Pb-Free)	27533	2500/Tape & Reel
MC33275DT-3.3G			369A	DPAK (Pb-Free)	27533G	75 Units/Rail
MC33275DT-3.3RKG	3.3 V (Fixed Voltage)		369A	DPAK (Pb-Free)	27533G	2500/Tape & Reel
MC33275ST-3.3T3G		2% Tolerance at T, from -40°C to +125°C	318E	SOT-223 (Pb-Free)	27533	4000/Tape & Reel
NCV33275ST3.3T3G*	-	1% Tolerance at T _A = 25°C	318E	SOT-223 (Pb-Free)	27533	4000/Tape & Reel
MC33275MN-3.3R2G	-		488AF	DFN-8 (Pb-Free)	27330	3000/Tape & Reel
MC33275D-5.0G		1% Tolerance at T _A = 25°C	751	SOIC-8 (Pb-Free)	27550	98 Units/Rail
MC33275D-5.0R2G	-		751	SOIC-8 (Pb-Free)	27550	2500/Tape & Reel
MC33275DT-5.0G	5.0 V		369A	DPAK (Pb-Free)	27550G	75 Units/Rail
MC33275DT-5.0RKG	(Fixed Voltage)	2% Tolerance at	369A	DPAK (Pb-Free)	27550G	2500/Tape & Reel
MC33275MN-5.0R2G	1	T _J from -40°C to +125°C 1% Tolerance at T _A = 25°C	488AF	DFN-8 (Pb-Free)	27550	3000/Tape & Reel
MC33275ST-5.0T3G	1	A =	318E	SOT-223 (Pb-Free)	27550	4000/Tape & Reel
NCV33275ST-5.0T3G*	1		318E	SOT-223 (Pb-Free)	27550	4000/Tape & Reel

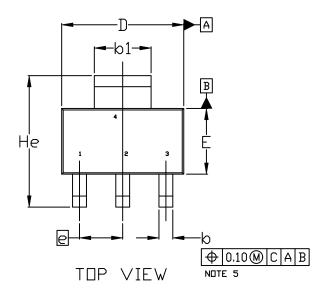
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

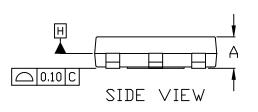
^{*}NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

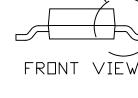


SOT-223 (TO-261) CASE 318E-04 ISSUE R

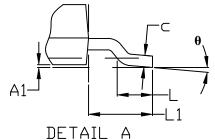
DATE 02 OCT 2018







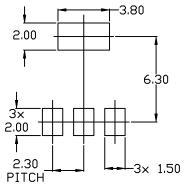
SEE DETAIL A



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D & E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
 MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.200MM PER SIDE.
- 4. DATUMS A AND B ARE DETERMINED AT DATUM H.
- 5. ALLIS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.
- 6. POSITIONAL TOLERANCE APPLIES TO DIMENSIONS 6 AND 61.

	MILLIMETERS			
DIM	MIN.	N□M.	MAX.	
Α	1.50	1.63	1.75	
A1	0.02	0.06	0.10	
b	0.60	0.75	0.89	
b1	2.90	3.06	3.20	
C	0.24	0.29	0.35	
D	6.30	6.50	6.70	
E	3.30	3.50	3.70	
е		2,30 BSC	,	
L	0.20			
L1	1.50	1.75	2.00	
He	6.70	7.00	7.30	
θ	0°		10°	



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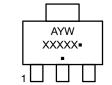
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DATE 02 OCT 2018

STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR	STYLE 2: PIN 1. ANODE 2. CATHODE 3. NC 4. CATHODE	STYLE 3: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN	STYLE 4: PIN 1. SOURCE 2. DRAIN 3. GATE 4. DRAIN	STYLE 5: PIN 1. DRAIN 2. GATE 3. SOURCE 4. GATE
STYLE 6: PIN 1. RETURN 2. INPUT 3. OUTPUT 4. INPUT	STYLE 7: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 4. CATHODE	STYLE 8: CANCELLED	STYLE 9: PIN 1. INPUT 2. GROUND 3. LOGIC 4. GROUND	STYLE 10: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE
STYLE 11: PIN 1. MT 1 2. MT 2 3. GATE 4. MT 2	STYLE 12: PIN 1. INPUT 2. OUTPUT 3. NC 4. OUTPUT	STYLE 13: PIN 1. GATE 2. COLLECTOR 3. EMITTER 4. COLLECTOR		

GENERIC MARKING DIAGRAM*



A = Assembly Location

Y = Year W = Work Week

XXXXX = Specific Device Code

= Pb-Free Package

(Note: Microdot may be in either location)
*This information is generic. Please refer to
device data sheet for actual part marking.
Pb-Free indicator, "G" or microdot "•", may
or may not be present. Some products may
not follow the Generic Marking.

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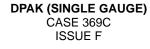
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ROTATED 90° CW

STYLE 1:

STYLE 2:





DATE 21 JUL 2015

- IOTES. 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: INCHES. 3. THERMAL PAD CONTOUR OPTIONAL WITHIN DI-

- MENSIONS b3, L3 and Z.

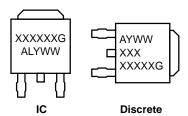
 Jimensions b And E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.

 MENSIONS D AND E ARE DETERMINED AT THE
- OUTERMOST EXTREMES OF THE PLASTIC BODY.

 6. DATUMS A AND B ARE DETERMINED AT DATUM
- 7. OPTIONAL MOLD FEATURE.

	INCHES		MILLIM	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.028	0.045	0.72	1.14
b3	0.180	0.215	4.57	5.46
С	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
е	0.090	BSC	2.29	BSC
Н	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.114	REF	2.90 REF	
L2	0.020	BSC	0.51	BSC
L3	0.035	0.050	0.89	1.27
L4		0.040		1.01
Z	0.155		3.93	

GENERIC MARKING DIAGRAM*



XXXXXX = Device Code = Assembly Location Α = Wafer Lot L

Υ = Year WW = Work Week G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking.

В L3 Ζ Ո DETAIL A NOTE 7 **BOTTOM VIEW** Cb2 е SIDE VIEW | \oplus | 0.005 (0.13) lacktriangle C **TOP VIEW** Z Ħ L2 GAUGE C SEATING PLANE **BOTTOM VIEW** Α1 ALTERNATE CONSTRUCTIONS **DETAIL A**

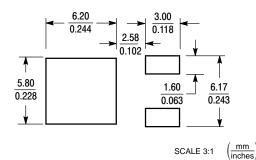
3. EMITTER	3. SOURCE	 ANODE CATHODE 	3. GATE	3. CATHODE
4. COLLECTOR	4. DRAIN		4. ANODE	4. ANODE
3. GATE 3. EMI	LECTOR 2. TTER 3.	N/C PIN CATHODE ANODE	E 9: 1. ANODE 2. CATHODE 3. RESISTOR ADJUST 4. CATHODE	STYLE 10: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. ANODE

STYLE 4:

STYLE 5:

STYLE 3:

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DESCRIPTION:	DPAK SINGLE GAUGE SURFACE MOUNT		PAGE 1 OF 2	
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STATUS:	ON SEMICONDUCTOR STANDARD	accessed directly from the Document versions are uncontrolled except		
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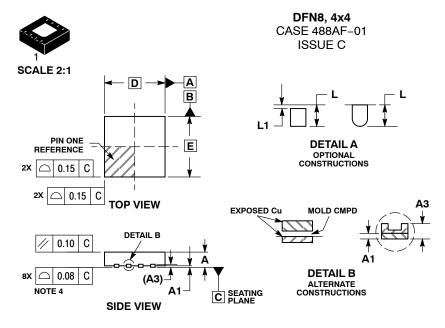


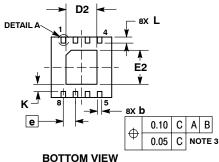
DOCUMENT	NUMBER:
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PAGE 2 OF 2

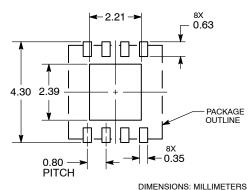
ISSUE	REVISION	DATE			
0	RELEASED FOR PRODUCTION. REQ. BY L. GAN	24 SEP 2001			
Α	ADDED STYLE 8. REQ. BY S. ALLEN.	06 AUG 2008			
В	ADDED STYLE 9. REQ. BY D. WARNER.	16 JAN 2009			
С	ADDED STYLE 10. REQ. BY S. ALLEN.	09 JUN 2009			
D	RELABELED DRAWING TO JEDEC STANDARDS. ADDED SIDE VIEW DETAIL A. CORRECTED MARKING INFORMATION. REQ. BY D. TRUHITTE.	29 JUN 2010			
E	ADDED ALTERNATE CONSTRUCTION BOTTOM VIEW. MODIFIED DIMENSIONS b2 AND L1. CORRECTED MARKING DIAGRAM FOR DISCRETE. REQ. BY I. CAMBALIZA.	06 FEB 2014			
F	ADDED SECOND ALTERNATE CONSTRUCTION BOTTOM VIEW. REQ. BY K. MUSTAFA.	21 JUL 2015			

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SOLDERING FOOTPRINT*



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DATE 15 JAN 2009

NOTES:

- DIMENSIONS AND TOLERANCING PER
- DIMENSIONS AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30MM FROM TERMINAL TIP.
 COPLANARITY APPLIES TO THE EXPOSED
- PAD AS WELL AS THE TERMINALS.
 DETAILS A AND B SHOW OPTIONAL CON-STRUCTIONS FOR TERMINALS.

	MILLIMETERS				
DIM	MIN	MAX			
Α	0.80	1.00			
A1	0.00	0.05			
А3	0.20 REF				
b	0.25 0.35				
D	4.00 BSC				
D2	1.91 2.21				
E	4.00 BSC				
E2	2.09	2.39			
е	0.80 BSC				
K	0.20				
Ĺ	0.30	0.50			
L1		0.15			

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code = Assembly Location

Α = Wafer Lot Т Υ = Year W = Work Week

= Pb-Free Package (Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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SOIC-8 NB CASE 751-07 **ISSUE AK**

DATE 16 FEB 2011



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.80	5.00	0.189	0.197
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
Н	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
М	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*



^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code = Assembly Location

= Wafer Lot = Year = Work Week

= Pb-Free Package



XXXXXX = Specific Device Code = Assembly Location Α

= Year ww = Work Week

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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SOIC-8 NB CASE 751-07 ISSUE AK

DATE 16 FEB 2011

STYLE 3: PIN 1. DRAIN, PIE #1 CTOR, #1 CTOR, #2 CTOR, #1 CTOR, #2 CTOR, #2 CTOR, #2 CTOR, #2 CTOR, #1	2. ANODE 3. ANODE 4. ANODE 5. ANODE 6. ANODE 7. ANODE 8. COMMON CATHODE STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 3. BASE, #2 4. COLLECTOR, #2 5. COLLECTOR, #2 6. EMITTER, #1 Vd STYLE 12: PIN 1. SOURCE 2. SOURCE 3. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN 8. TYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #1
E PIN 1. INPUT 2. EXTERNAL BY 3. THIRD STAGE 4. GROUND E 5. DRAIN 6. GATE 3 7. SECOND STAGE 8. FIRST STAGE STYLE 11: ID PIN 1. SOURCE 1 2. GATE 1 T 3. SOURCE 2 ID 4. GATE 2 ID 5. DRAIN 2 6. DRAIN 2 7. DRAIN 1 ID 8. DRAIN 1 ID	PIN 1. COLLECTOR, DIE #1 2. BASE, #1 3. BASE, #2 4. COLLECTOR, #2 5. COLLECTOR, #2 6. EMITTER, #2 7. EMITTER, #1 Vd 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE 2. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN 8. TYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #2
ID PIN 1. SOURCE 1 2. GATE 1 T 3. SOURCE 2 ID 4. GATE 2 ID 5. DRAIN 2 6. DRAIN 2 7. DRAIN 1 ID 8. DRAIN 1 STYLE 15: RCE PIN 1. ANODE 1 E 2. ANODE 1 RCE 3. ANODE 1	PIN 1. SOURCE 2. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #2
STYLE 15: RCE PIN 1. ANODE 1 E 2. ANODE 1 RCE 3. ANODE 1	PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #2
N 7. CATHODE, CON N 8. CATHODE, CON	MMON 5. COLLECTOR, DIE #2 MMON 6. COLLECTOR, DIE #2 MMON 7. COLLECTOR, DIE #1 MMON 8. COLLECTOR, DIE #1
STYLE 19: PIN 1. SOURCE 1 E 2. GATE 1 E 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. MIRROR 2 DE 7. DRAIN 1 DE 8. MIRROR 1	STYLE 20: PIN 1. SOURCE (N) 2. GATE (N) 3. SOURCE (P) 4. GATE (P) 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN
STYLE 23: E1 PIN 1. LINE 1 IN DN CATHODE/VCC 2. COMMON ANC DN CATHODE/VCC 3. COMMON ANC E3 4. LINE 2 IN DN ANODE/GND 5. LINE 2 OUT E4 6. COMMON ANC E5 7. COMMON ANC DN ANODE/GND 8. LINE 1 OUT	ODE/GND 2. EMITTER ODE/GND 3. COLLECTOR/ANODE
STYLE 27: PIN 1. ILIMIT 2. OVLO 3. UVLO 4. INPUT+ 5. SOURCE 6. SOURCE 6. SOURCE 7. SOURCE 8. DRAIN	STYLE 28: PIN 1. SW_TO_GND 2. DASIC_OFF 3. DASIC_SW_DET 4. GND 5. V MON 6. VBULK 7. VBULK 8. VIN
1 1	
;	STYLE 27: PIN 1. ILIMIT 2. OVLO 3. UVLO 4. INPUT+ E 5. SOURCE E 6. SOURCE E 7. SOURCE 8. DRAIN

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